Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!

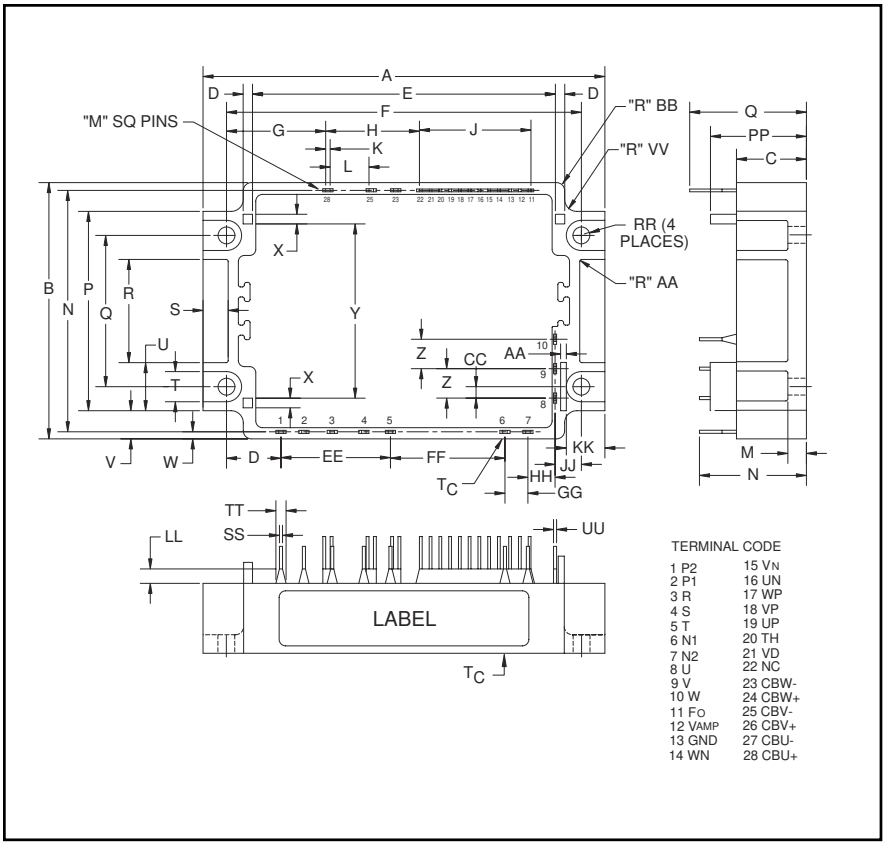
Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832
Email & Skype: info@chipsmall.com Web: www.chipsmall.com
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China

Powerex, Inc., 200 E. Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

Intellimod™ Module

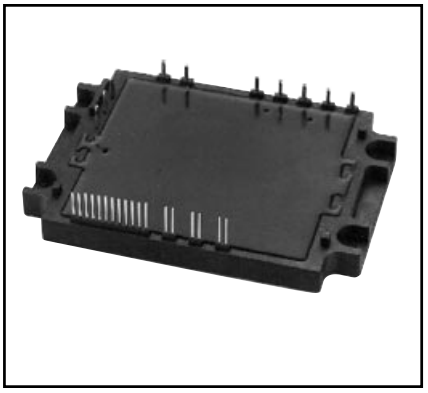
Application Specific IPM
5 Amperes/1200 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	4.06 +0/-0.02	103.0+0/-0.4
B	2.87 +0/-0.02	73.0 +0/-0.4
C	0.35	9.0
D	0.10	2.5
E	3.11	79.0
F	3.74±0.01	95±0.2
G	1.32	33.5
H	0.95	24.0
J	0.87	22.0
K	0.08	2.0
L	0.24	6.0
M	0.02 Sq.	0.5 Sq.
N	2.72	69.0
P	2.13	54.0
Q	1.54±0.01	39.0±0.2
R	0.95	24.0
S	0.26	6.5
T	0.35	9.0
U	0.59	15.0
V	0.37	9.5
W	0.08	2.0
X	0.12	3.0

Dimensions	Inches	Millimeters
Y	1.81	46.0
Z	0.30	7.62
AA	0.08 Rad.	2.0 Rad.
BB	0.04 Rad.	1.0 Rad.
CC	0.14	3.5
DD	0.47	12.0
EE	1.20	30.48
FF	0.90	22.86
GG	0.30	7.62
HH	0.51	13.4
JJ	0.35	9.0
KK	0.34	8.5
LL	0.08	2.0
MM	0.12	3.0
NN	0.67	17.0
PP	0.49	12.5
QQ	0.80	20.4
RR	0.16	4.0
SS	0.06	1.4
TT	0.12	3.0
UU	0.04	1.0
VV	0.16	4.0



Description:
Powerex Application Specific IPMs (ASIPMs) are inteligent power modules that integrate power devices, gate drive and protection circuitry in a compact package for use in small inverter applications up to 20kHz. Use of application specific HVICs allow the designer to reduce inverter size and overall design time.

Features:
- ☐ Rectifier Bridge for 3-phase AC-to-DC Power Conversion
- ☐ 3-phase IGBT Inverter Bridge
- ☐ Integrated HVICs for Gate Drive, Protection and System Control Functions
- ☐ Built-in Thermistor
- ☐ Direct Connection to DSP/CPU

Applications:
- ☐ Smart Motors
- ☐ General Purpose Inverters
- ☐ Small Motor Control

Ordering Information:
PS12033 is a 1200V, 5 Ampere Application Specific Power Module.

PS12033
Intellimod™ Module
Application Specific IPM
5 Amperes/1200 Volts

Absolute Maximum Ratings, T_j = 25°C unless otherwise specified

Characteristics	Symbol	PS12033	Units
Power Device Junction Temperature*	T_j	-20 to 125	°C
Storage Temperature	T_{stg}	-40 to 125	°C
Case Operating Temperature (See T_C Measure Point Illustration)	T_C	-20 to 100	°C
Mounting Torque, M3.5 Mounting Screws	—	11.25	in-lb
Module Weight (Typical)	—	127	Grams
Isolation Voltage**	V_{ISO}	2500	Volts

*The indicated values are specified considering the safe operation of all the parts within the ASIPM. The maximum rating for the ASIPM power chips (IGBT & FWDi) is T_j < 150.
**60 Hz sinusoidal AC applied between all terminals and the base plate for 1 minute.

IGBT Inverter Sector

Supply Voltage (Applied between P2 - N2)	V_{CC}	900	Volts
Supply Voltage, Surge (Applied between P2 - N2, Surge-Value)	$V_{CC(surge)}$	1000	Volts
Each IGBT Collector-Emitter Static Voltage (Applied between P2-U·V·W, U·V·W-N2)	V_P or V_N	1200	Volts
Each IGBT Collector-Emitter Switching Voltage (Applied between P2-U·V·W, U·V·W-N2 (Pulse))	$V_{P(S)}$ or $V_{N(S)}$	1200	Volts
Each IGBT Collector Current, T_C = 25°C, "( )" means I_C Peak Value	$\pm I_C$ ($\pm I_{CP}$)	±5 (±10)	Amperes

Converter Sector

Repetitive Peak Reverse Voltage	V_{RRM}	1600	Volts
Recommended AC Input Voltage	E_a	440	Vrms
DC Output Current (3-phase Rectifying Circuit)	I_O	12	A
Surge (Non-repetitive) Forward Current (1 Cycle at 60Hz, Peak Value Non-repetitive)	I_{FSM}	120	A
I^2t for Fusing (Value for One Cycle of Surge Current)	I^2t	60	A^2s

Control Sector

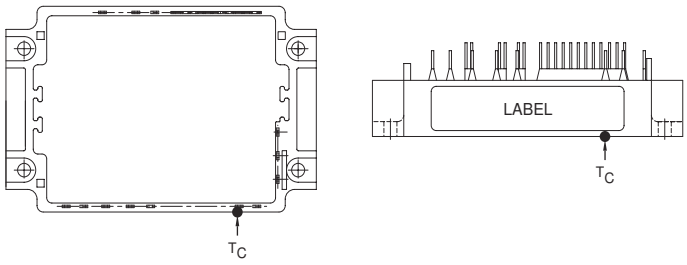
Supply Voltage	V_D, V_{DB}	-0.5 ~ 20	Volts
Input Signal Voltage	V_{CIN}	-0.5 ~ 7.5	Volts
Fault Output Supply Voltage	V_{FO}	-0.5 ~ 7.5	Volts
Fault Output Current	I_{FO}	15	mA
DC-link IGBT Current Signal Amp Output Current	I_{AMP}	1	mA

PS12033
Intellimod™ Module
Application Specific IPM
5 Amperes/1200 Volts

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C = 5A, T_j = 25°C, V_D = V_{DB} = 15V, Input = ON (Shunt Voltage Drop Not Included)	—	—	3.6	Volts
Diode Forward Voltage	V_{EC}	T_j = 25°C, -I_C = 5A	—	—	3.5	Volts
Converter Diode Voltage	V_{FR}	T_j = 25°C, I_{FR} = 5A	—	—	1.5	Volts
Converter Diode Reverse Current	I_{RRM}	V_R = V_{RRM}, T_j = 125°C	—	—	8.0	mA
Switching Times	t_{on}	1/2 Bridge Inductive, Input = 5V ↔ 0V,	0.3	1.2	2.0	µS
	$t_{C(on)}$	V_{CC} = 600V, I_C = 5A, T_j = 125°C,	—	0.5	1.4	µS
	t_{off}	V_D = 15V, V_{DB} = 15V	—	2.2	4.0	µS
	$t_{C(off)}$	Note: t_{on}, t_{off} include delay time of	—	0.9	1.6	µS
FWDi Reverse Recovery Time	t_{rr}	the internal control circuit.	—	0.2	—	µS
Short Circuit Endurance (Output, Arm, and Load Short-circuit Modes)		@V_{CC} ≤ 800V, Input = 5V → 0V (One-shot), -20°C ≤ $T_{j(start)}$ ≤ 125°C, 13.5V ≤ V_D = V_{DB} ≤ 16.5V	• No Destruction • F_O Output by Protection Operation			
Switching SOA		@V_{CC} ≤ 800V, Input = 5V → 0V, T_j ≤ 150°C, I_C < OC Trip Level, 13.5V ≤ V_D = V_{DB} ≤ 16.5V	• No Destruction • No Protecting Operation • No F_O Output			

T_C Measure Point



PS12033
Intellimod™ Module
Application Specific IPM
5 Amperes/1200 Volts

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Circuit Current (Average)	I_D	T_j = 25°C, V_D = 15V, V_{IN} = 5V	—	—	50	mA
	I_{DB}	T_j = 25°C, V_D = V_{DB} = 15V, V_{IN} = 5V	—	—	5	mA
Input ON Threshold Voltage	$V_{th(on)}$		0.8	1.4	2.0	Volts
Input OFF Threshold Voltage	$V_{th(off)}$		2.5	3.0	4.0	Volts
Input Pull-up Resistor	Ri	Applied between Input Terminal-inside Power Supply	—	50	—	kΩ
PWM Input Frequency	f_{PWM}	$T_C \leq$ 100°C, $T_j \leq$ 125°C	—	10	15	kHz
Arm Shoot-through Blocking Time*	t_{DEAD}	Relates to Corresponding Inputs T_C = -20°C ~ 100°C	4.0	—	—	µS
Input Interlock Sensing	t_{int}	Relates to Corresponding Input	—	100	—	ns
Inverter DC-link IGBT Current	V_{amp} 100%	$I_C = I_{OP(100\%)}$, V_D = 15V, T_j = 25°C	1.5	2.0	2.5	Volts
Sense Voltage Output Signal**	V_{amp} 200%	$I_C = I_{OP(200\%)}$, V_D = 15V, T_j = 25°C	3.0	4.0	5.0	Volts
Inverter DC-link IGBT Current	V_{amp} 250%	$I_C = I_{OP(250\%)}$, V_D = 15V	5.0	—	—	Volts
Sense Voltage Output Limit**	V_{amp} 0%	$I_C = I_{OP(0\%)}$, V_D = 15V	—	50	100	mV
Over-current Trip Level	OC	T_j = 25°C	7.6	9.1	—	Amperes
Over-current Delay Time	t_{OC}		—	10	—	µS
Short-circuit Trip Level	SC		—	13.7	—	Amperes
Short-circuit Delay Time	t_{SC}		—	2	—	µs
Supply Circuit Under-voltage Protection — Trip Level	UV_D	$T_C = T_j$ = 25°C	11.0	12.0	12.75	Volts
Supply Circuit Under-voltage Protection — Reset Level	UV_{Dr}		11.5	12.5	13.25	Volts
Supply Circuit Under-voltage Protection — Trip Level	UV_{DB}		10.1	10.8	11.6	Volts
Supply Circuit Under-voltage Protection — Reset Level	UV_{DBr}		10.6	11.3	12.1	Volts
Supply Circuit Under-voltage Protection — Delay Time	t_{dV}		—	10	—	µS
Fault Output Pulse Width***	t_{FO}	T_j = 25°C	1.0	1.8	—	mS
Fault Output Current***	$I_{Fo(H)}$	Open Collector Output	—	—	1	µA
	$I_{Fo(L)}$		—	—	15	mA
Thermistor Resistance	R_{TO}	T_O = 25°C (298K)	9.5	10	10.5	kΩ
Material Constant****	β	T_1 = 25°C, T_2 = 50°C	—	3450	—	K

* The dead-time has to be set externally by the CPU; it is not part of the ASIPM internal functions.
**Refer to the graph on next page.
***Fault output signalling is given only when the internal OC, SC, and UV protection circuits are activated. The OC, SC and UV protection (and fault output) operate for the lower arms only. The OC and SC protection fault output is given in a pulse format while that of UV protection is maintained throughout the duration of the under-voltage condition.

$$****T = \frac{1}{\frac{1}{\beta} \cdot \ln\left[\frac{R_T}{R_{TO}}\right] + \frac{1}{T_O}}$$

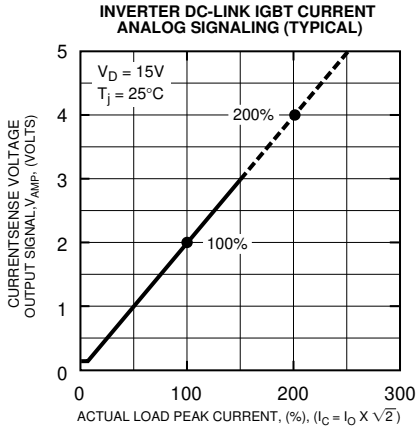
PS12033
Intellimod™ Module
Application Specific IPM
5 Amperes/1200 Volts

Thermal Characteristics

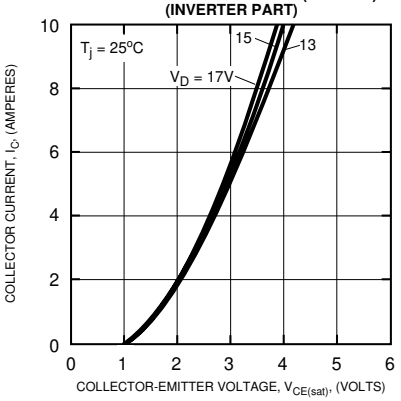
Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case	$R_{th(j-c)Q}$	Each IGBT	—	—	2.5	°C/Watt
	$R_{th(j-c)D}$	Each FWDi	—	—	4.5	°C/Watt
	$R_{th(j-c)DR}$	Each Converter	—	—	2.5	°C/Watt
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module. Thermal Grease Applied	—	—	0.05	°C/Watt

Recommended Conditions for Use

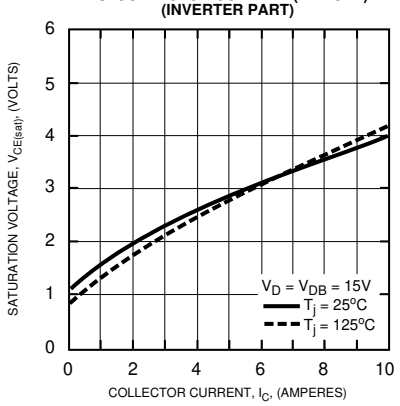
Characteristic	Symbol	Condition	Min.	Typ.	Value	Units
Supply Voltage	V_{CC}	Applied across P2-N2 Terminals	—	600	800	Volts
Control Supply Voltage	V_D	Applied between V_D-GND	13.5	15.0	16.5	Volts
	V_{DB}	Applied between CBU+ & CBU-, CBV+ & CBV-, CBW+ & CBW-	13.5	15.0	16.5	Volts
Control Supply dv/dt	dV_D/dt, dV_{DB}/dt		-1	—	1	V/µs
Input ON Voltage	$V_{CIN(on)}$	Applied between U_P, V_P, W_P, U_N, V_N, W_N-GND	0	—	0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$		4.0	—	5.0	Volts
Module Case Operating Temperature	T_C		—	—	100	°C
PWM Input Frequency	f_{PWM}	$T_C \leq 100°C$, $T_j \leq 125°C$	—	—	15	kHz
Allowable Minimum Input On-pulse Width	t_{XX}		1	—	—	µS
Arm Shoot-through Blocking Time	t_{DEAD}	Relate to Corresponding Inputs	4.0	—	—	µS



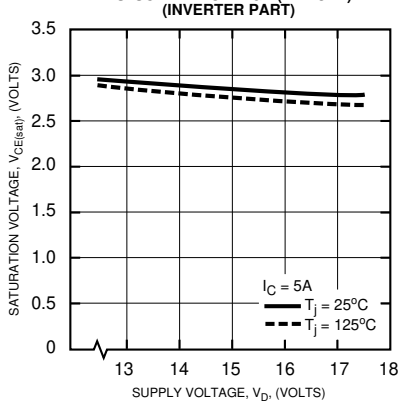
OUTPUT CHARACTERISTICS (TYPICAL) (INVERTER PART)



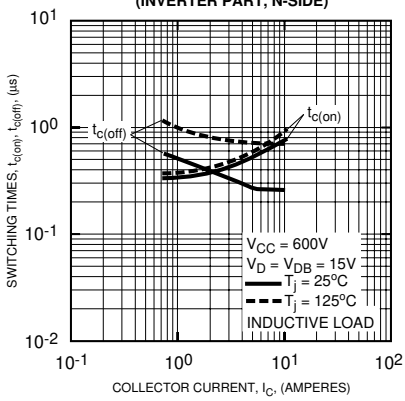
COLLECTOR-EMITTER SATURATION VOLTAGE VS. COLLECTOR CURRENT (TYPICAL) (INVERTER PART)



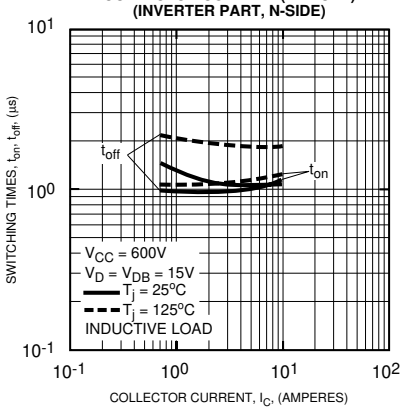
COLLECTOR-EMITTER SATURATION VOLTAGE VS. SUPPLY VOLTAGE (TYPICAL) (INVERTER PART)



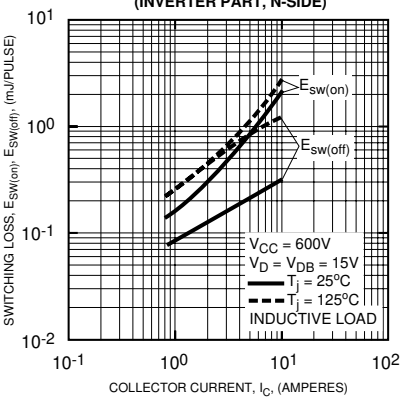
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL) (INVERTER PART, N-SIDE)



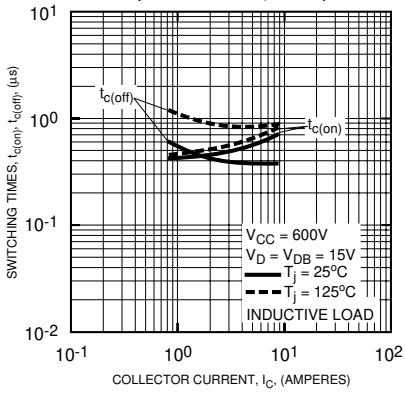
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL) (INVERTER PART, N-SIDE)



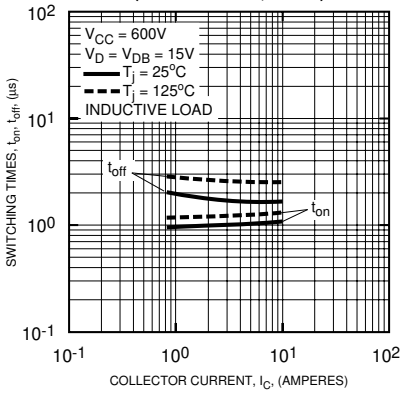
SWITCHING LOSS CHARACTERISTICS (TYPICAL) (INVERTER PART, N-SIDE)



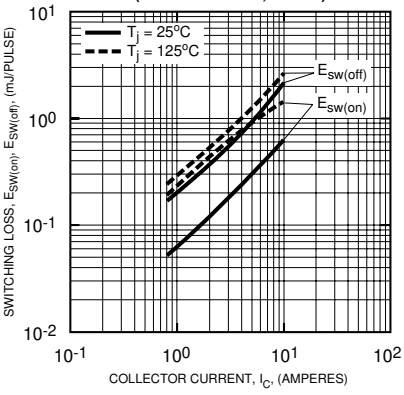
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL) (INVERTER PART, P-SIDE)



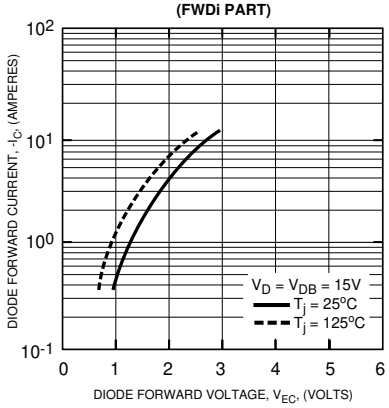
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL) (INVERTER PART, P-SIDE)



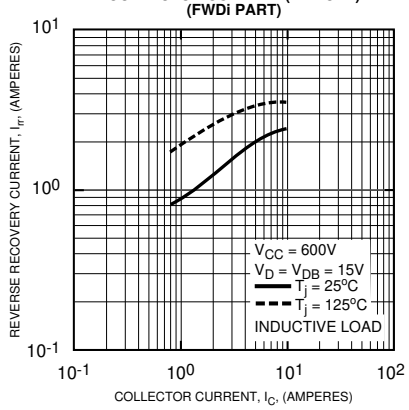
SWITCHING LOSS CHARACTERISTICS (TYPICAL) (INVERTER PART, P-SIDE)



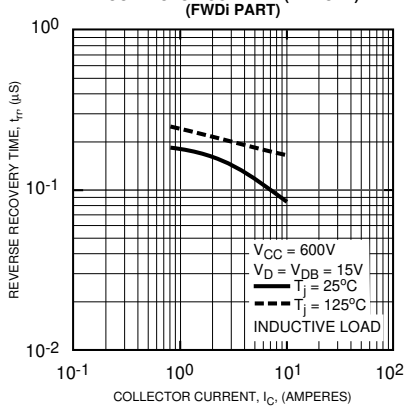
DIODE FORWARD CHARACTERISTICS (FWDi PART)



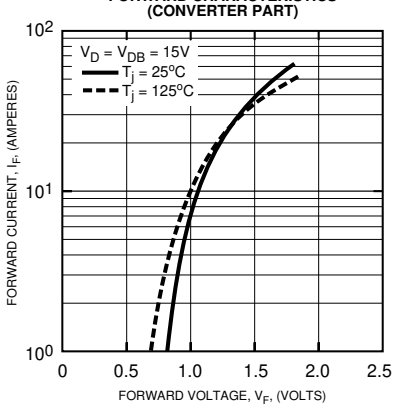
REVERSE RECOVERY CURRENT VS. COLLECTOR CURRENT (TYPICAL) (FWDi PART)



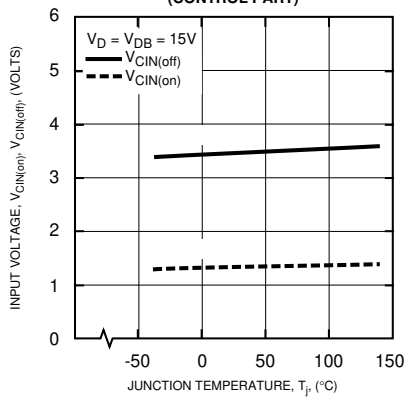
REVERSE RECOVERY TIME VS. COLLECTOR CURRENT (TYPICAL) (FWDi PART)



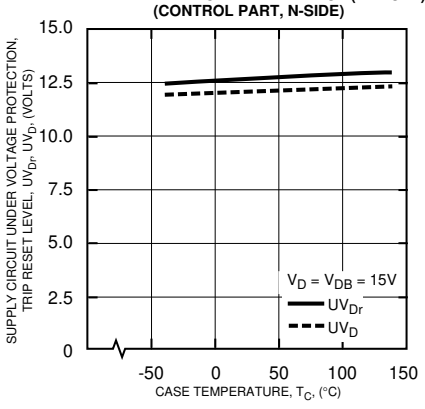
FORWARD CHARACTERISTICS (CONVERTER PART)



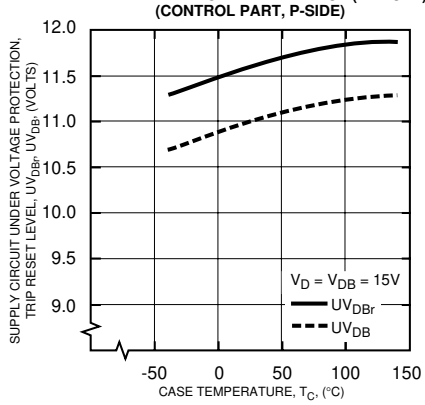
INPUT VOLTAGE VS. JUNCTION TEMPERATURE (TYPICAL) (CONTROL PART)



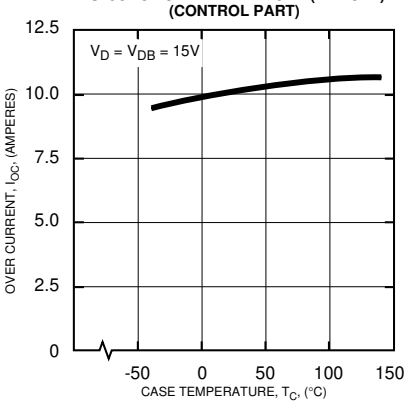
CONTROL SUPPLY VOLTAGE TRIP-RESET LEVEL TEMPERATURE DEPENDENCY (TYPICAL) (CONTROL PART, N-SIDE)



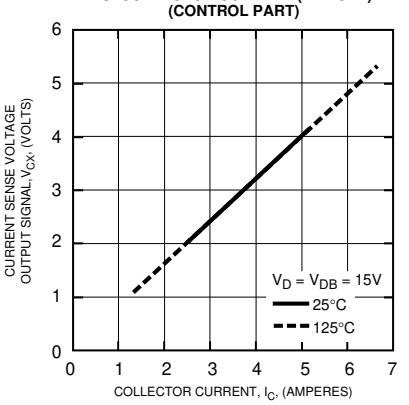
CONTROL SUPPLY VOLTAGE TRIP-RESET LEVEL TEMPERATURE DEPENDENCY (TYPICAL) (CONTROL PART, P-SIDE)



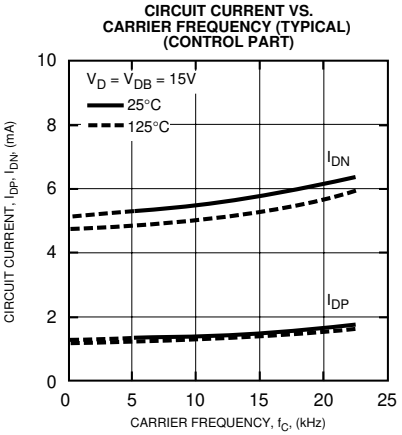
SHORT-CIRCUIT TRIP LEVEL VS. JUNCTION TEMPERATURE (TYPICAL) (CONTROL PART)



INVERTER DC-LINK IGBT CURRENT VS. COLLECTOR CURRENT (TYPICAL) (CONTROL PART)



PS12033
Intellimod™ Module
Application Specific IPM
5 Amperes/1200 Volts



Functional Block Diagram